

General Description

The WSD30140DN56 is the highest performance trench N-Ch MOSFET with extreme high celldensity ,which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSD30140DN56 meet the RoHS and Green Product requirement , 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

Product Summery

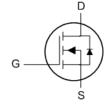
BVDSS	RDSON	ID
30V	1.7mΩ	85A

Applications

- High Frequency Point-of-Load Synchronous Buck Converter
- Networking DC-DC Power System
- Power Tool Application

DFN5X6-8 Pin Configuration





Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _C =25℃	Continuous Drain Current, V _{GS} @ 10V ^{1,7}	85	А
I _D @T _C =70℃	Continuous Drain Current, V _{GS} @ 10V ^{1,7}	65	А
I _{DM}	Pulsed Drain Current ²	300	Α
P _D @T _C =25°C	Total Power Dissipation ⁴	50	W
T _{STG}	Storage Temperature Range	-55 to 150	$^{\circ}$
T _J	Operating Junction Temperature Range	-55 to 150	$^{\circ}$

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-Ambient ¹		55	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case ¹		1.5	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25 $^{\circ}$ C , I _D =1mA		0.02		V/°C	
D	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =20A		1.7	2.4	mΩ	
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =4.5V , I _D =15A		2.5	3.3		
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}$, $I_D=250uA$	1.2	1.7	2.5	V	
	Drain Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =25 $^{\circ}$ C			1		
I _{DSS}	Drain-Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_J =55 $^{\circ}$ C			5	- uA	
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA	
gfs	Forward Transconductance V _{DS} =5V , I _D =20A			90		S	
Qg	Total Gate Charge (4.5V)			26			
Q _{gs}	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V , I _D =20A		9.5		nC	
Q _{gd}	Gate-Drain Charge			11.4			
$T_{d(on)}$	Turn-On Delay Time			11			
Tr	Rise Time V _{DD} =15V , V _{GEN} =10V ,			6		no	
$T_{d(off)}$	Turn-Off Delay Time	$R_G=3\Omega$, RL=0.75 Ω .		38.5		ns	
T_f	Fall Time			10			
Ciss	Input Capacitance			3000			
C _{oss}	Output Capacitance V _{DS} =15V , V _{GS} =0V , f=1MHz			1280		pF	
C _{rss}	Reverse Transfer Capacitance			160			

Diode Characteristics

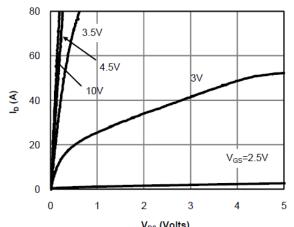
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _S	Continuous Source Current ^{1,6} V _G =V _D =0V , Force Current				85	Α
V_{SD}	Diode Forward Voltage ²	V_{GS} =0V , I_S =A , T_J =25 $^{\circ}$ C			1.2	V

A: The value of RθJA is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with TA=25°C. The value in any given application depends on the user's specific board design.

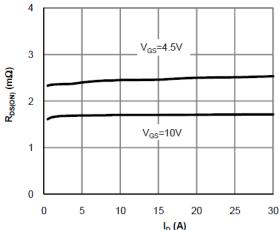
- B: Repetitive rating, pulse width limited by junction temperature.
- C: The current rating is based on the t≤ 10s junction to ambient thermal resistance rating.



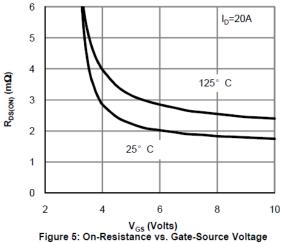
Typical Characteristics

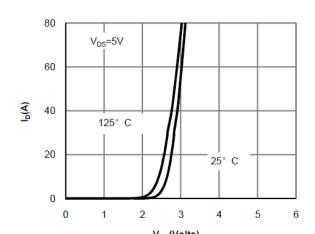


V_{DS} (Volts) Figure 1: On-Region Characteristics



l_D (A) Figure 3: On-Resistance vs. Drain Current and Gate Voltage





V_{GS}(Volts) Figure 2: Transfer Characteristics

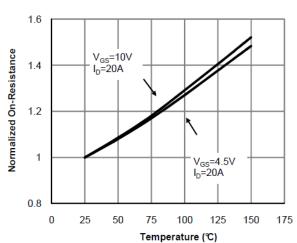
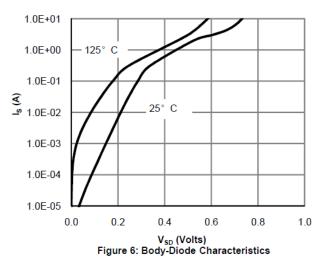
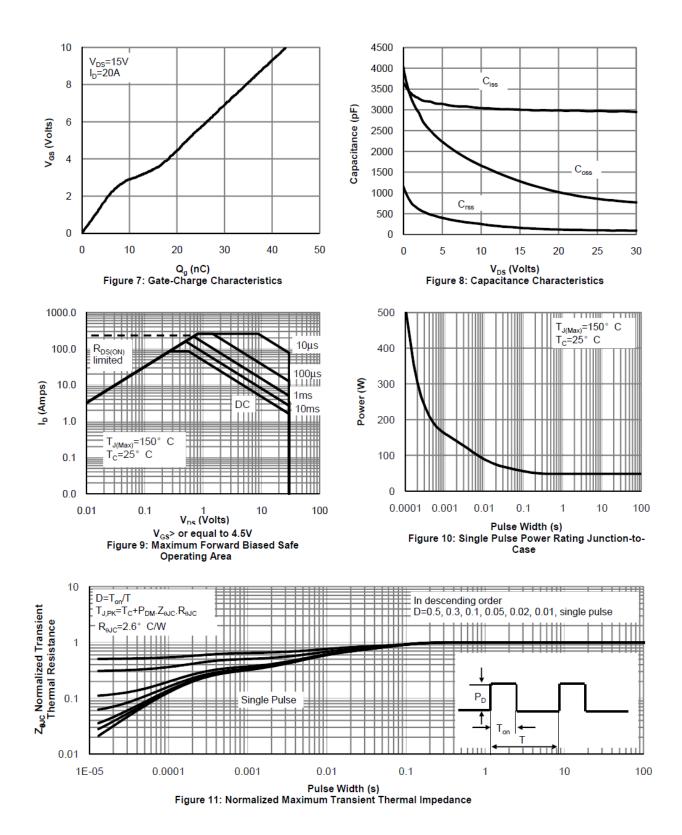


Figure 4: On-Resistance vs. Junction Temperature

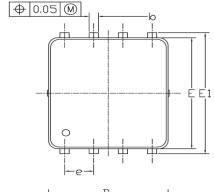


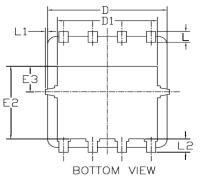


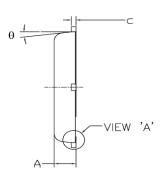


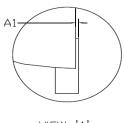


Package Information



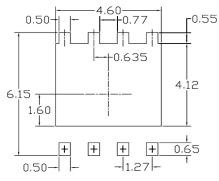






VIEW 'A' (SCALE 5:1)

RECOMMENDED LAND PATTERN



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES				
SYMBOLS	MIN	NOM	MAX	MIN	MAX			
A	0.85	0. 95	1.00	0.033	0.037 0.039			
A1	0.00		0.05	0.000		0.002		
b	0.30	0.40	0.50	0.012	0.016	0.020		
c	0.15	0. 20	0. 25	0.006	0.008	0.010		
D		5. 20 BSC			0.205 BSC			
D1	4.35 BSC				0.171 BSC			
E	5. 55 BSC				0.219 BSC			
E1	6.05 BSC				0.238 BSC			
E2	3.625 BSC				0.143 BSC			
E3	1.275 BSC				0.050 BSC			
e	1. 27 BSC			0.050 BSC				
L	0.45	0.55	0.65	0.018 0.022 0.02				
L1	0		0.15	0		0.006		
L2	0.68 REF			0.027 REF				
θ	0°		10°	0° 10°				

- UNIT: mm 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
- 2. CONTROLLING DIMENSION IS MILLIMETER.
- CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.



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